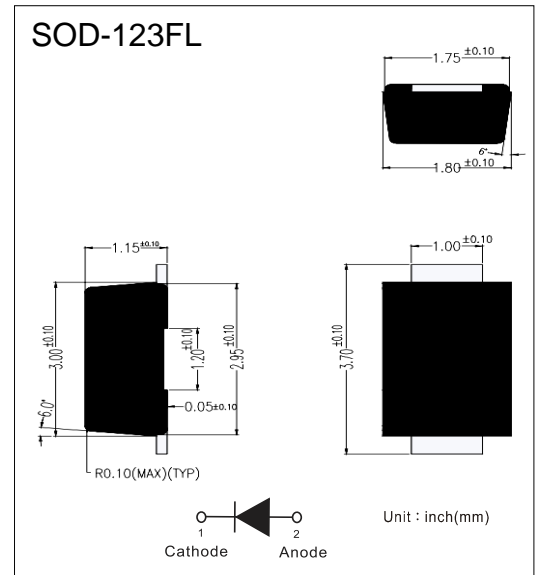


■ Features

- Glass passivated junction chip
- Ideal for automated placement
- Fast switching for high efficiency
- Comply with RoHS standard, halogen-free

■ Mechanical Data

- package:SOD-123FL
- Polarity: Indicated by cathode band
- Epoxy: UL 94V-0 rate flame retardant
- Mounting Position : Any



■ Maximum Ratings And Electrical Characteristics($T_A=25^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	U1A	U1B	U1D	U1G	U1J	U1K	U1M	UNIT
Maximum repetitive peak reverse voltage	VRRM	50	100	200	400	600	800	1000	V
Maximum RMS voltage	VRMS	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	VDC	50	100	200	400	600	800	1000	V
Maximum average forward rectified current	IF(AV)	1							A
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load	IFSM	30							A
Maximum instantaneous forward voltage (Note 1) @ 1 A	VF	1.0			1.7			V	
Maximum reverse current @ rated VR TJ=25°C TJ=125°C	IR	5					150		μA
Maximum reverse recovery time (Note 2)	t _{rr}	50			75			ns	
Typical junction capacitance (Note 3)	C _J	15			10			pF	
Typical thermal resistance	R _{θJL} R _{θJA}	27					75		°C/W
Operating junction temperature range	T _J	- 55 to +150							°C
Storage temperature range	TSTG	- 55 to +150							°C

Note 1: Pulse test with PW=300μs, 1% duty cycle

Note 2: Reverse Recovery Test Conditions: IF=0.5A, IR=1.0A, IRR=0.25A

Note 3: Measured at 1 MHz and Applied VR=4.0 Volts

■ Ratings And Characteristics Curves($T_A=25^{\circ}\text{C}$ unless otherwise noted)

FIG.1 MAXIMUM FORWARD CURRENT DERATING CURVE

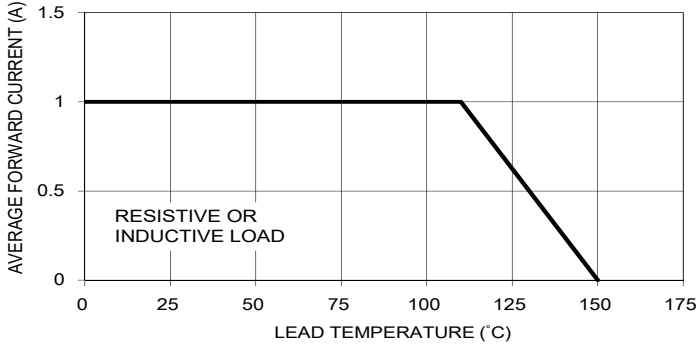


FIG. 2 MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

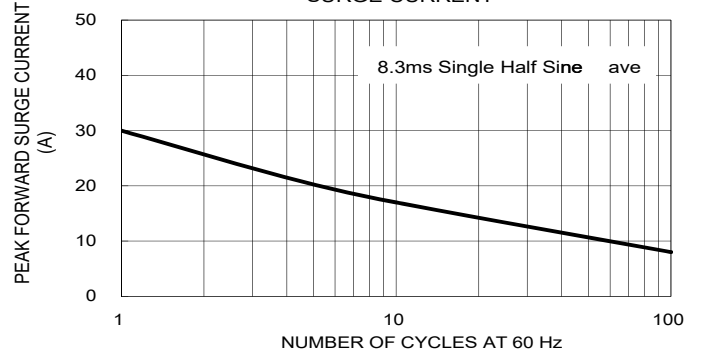


FIG. 3 TYPICAL FORWARD CHARACTERISTICS

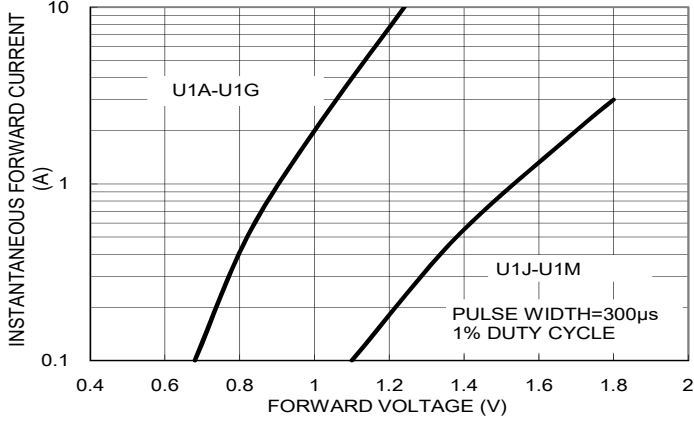


FIG. 4 TYPICAL REVERSE CHARACTERISTICS

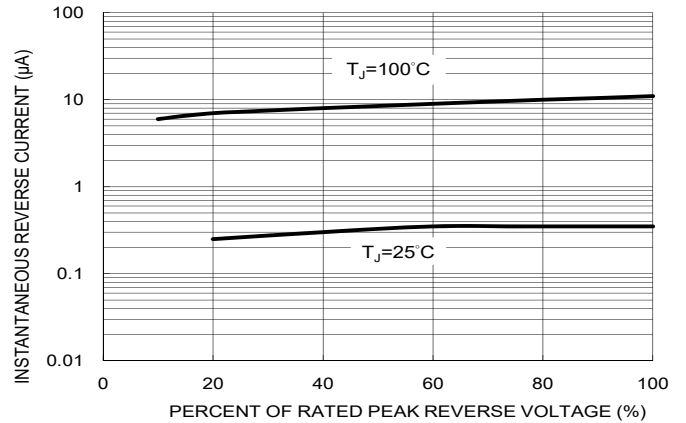


FIG. 5 TYPICAL JUNCTION CAPACITANCE

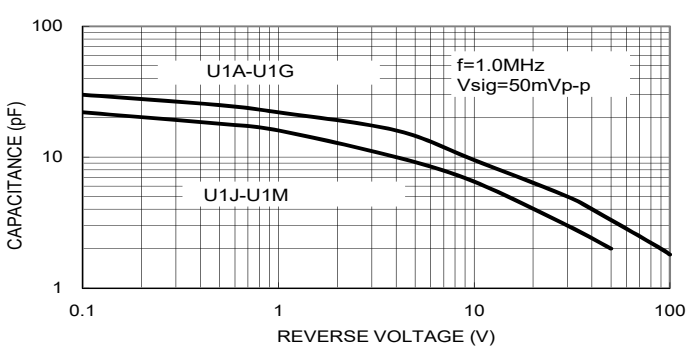


FIG. 6 TYPICAL TRANSIENT THERMAL IMPEDANCE

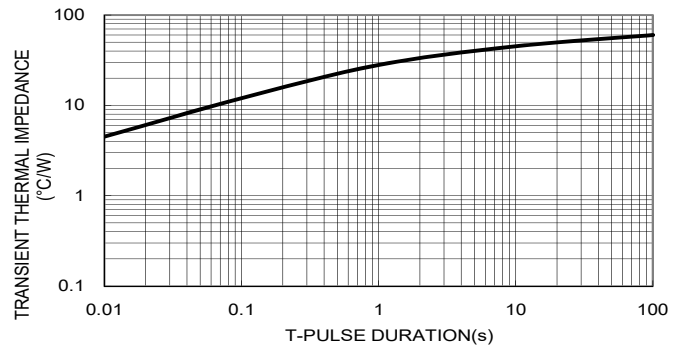
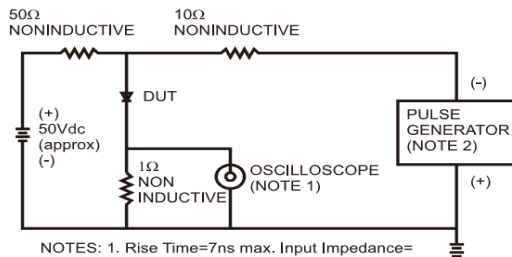


FIG.7- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



NOTES: 1. Rise Time=7ns max. Input Impedance=1 megohm 22pf
2. Rise Time=10ns max. Source Impedance=50 ohms

